

Part: Q6035NH5
 Series: Teccor® Alternistor Triac Devices
 Technology: Triacs

PARAMETERS		
Package Type	Pkg Type	Surface Mount
Mount Method	Mount	Surface Mount
Critical Rate-of-rise of On-state Current	di/dt (A/μs)	100
Critical rate-of-rise of off-state voltage	dv/dt @ 100°C (V/μs)	500
Critical rate-of-rise of off-state voltage	dv/dt @ 125°C (V/μs)	400
Critical Rate-of-rise of Commutation Voltage of a Triac (commutating dv/dt)	dv/dt(c) TYP (V/μs)	20
Repetitive Peak off-state Current	I _{DRM} @ 100°C max (mA)	0.5000
Repetitive Peak off-state Current	I _{DRM} @ 110°C MAX (mA)	0.0000
Repetitive Peak off-state Current	I _{DRM} @ 125°C max (mA)	2.0000
Repetitive Peak off-state Current	I _{DRM} @ 25°C max (mA)	0.0500
Gate Trigger Current - Q4	I _{GT} Q4 TYP (mA)	0
Peak gate trigger current	I _{GT} M (A)	2.0000
RMS Surge (Non-repetitive) On-state Fusing Current	I ² t (A ² Sec)	508.0000
Average Gate Power Dissipation	P _{G(AV)} (Watts)	0.5000
Peak Gate Power Dissipation	P _{GM} (Watts)	20
Package Size / Form Factor	Size	TO-263
Gate-controlled Turn-on time	T _{GT} TYP (μs)	3.0000
Maximum Gate Trigger Voltage	V _{GT} MAX @ 125°C (V)	0.2000
Gate Trigger Voltage	V _{GT} MAX @ 25°C (V)	2.0000
Peak on-state voltage a maximum rated RMS current	V _{TM} (V)	1.5000
Maximum On-state Current	I _{T(RMS)} MAX (A)	35
Repetitive Peak Off-state Voltage	V _{DRM} MIN (V)	600
Gate Trigger Current - Q1	I _{GT} Q1 MAX (mA)	50
Gate Trigger Current - Q2	I _{GT} Q2 MAX (mA)	50
Gate Trigger Current - Q3	I _{GT} Q3 MAX (mA)	50
Gate Trigger Current - Q4	I _{GT} Q4 MAX (mA)	0
Maximum Holding Current	I _H MAX (mA)	75
Surge (Non-repetitive) On-state current	I _{TSM} @ 60Hz (A)	350
Surge (Non-repetitive) On-state current	I _{TSM} @ 50Hz (A)	290

